

# Continental Device India Limited







An IS/ISO 9002 and IECQ Certified Manufacturer

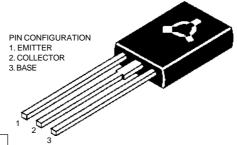
### TO-126 (SOT-32) Plastic Package

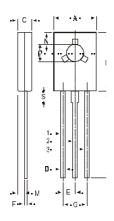
BD135, BD137, BD139

## BD135, 137, 139 NPN PLASTIC POWER TRANSISTORS

Complementary BD136, 138, 140

Medium Power Linear and Switching Applications





DIM	MIN.	MAX.		
2	14111111	1711 27		
A	7.4	7.8		
В	10.5	10.8		
С	2.4	2.7		
D	0.7	0.9		
Е	2.25 TYP.			
F	0.49	0.75		
G	4.5 TYP.			
L	15.7 TYP.			
М	1.27 TYP.			
N	3.75 TY <b>P</b> .			
P	3.0	3.2		
\$	2.5 TYP.			

ALL DIMENSIONS IN MM

#### ABSOLUTE MAXIMUM RATINGS

		135	137	139		
$V_{CBO}$	max.	45	60	100	V	
$V_{CEO}$	max.	45	60	<i>80</i>	V	
$I_C$	max.		1.5		$\boldsymbol{A}$	
$P_{tot}$	max.		12.5		W	
$T_{j}$	max.		<i>150</i>		${}^{\circ}\!C$	
3						
$V_{CEsat}$	max.		0.5		V	
$h_{\!F\!E}$	min.		40			
	max.		<i>250</i>			
	VCEO IC Ptot Tj	$V_{CEO}$ max. $I_C$ max. $P_{tot}$ max. $T_j$ max. $V_{CEsat}$ max. $h_{FE}$ min.	$egin{array}{lll} V_{CBO} & max. & 45 \\ V_{CEO} & max. & 45 \\ I_{C} & max. \\ P_{tot} & max. \\ T_{j} & max. \\ \hline V_{CEsat} & max. \\ h_{FE} & min. \\ \end{array}$	$egin{array}{llll} V_{CBO} & max. & 45 & 60 \\ V_{CEO} & max. & 45 & 60 \\ I_{C} & max. & 1.5 \\ P_{tot} & max. & 12.5 \\ T_{j} & max. & 150 \\ \hline & V_{CEsat} & max. & 0.5 \\ h_{FE} & min. & 40 \\ \hline \end{array}$	$egin{array}{llllllllllllllllllllllllllllllllllll$	$egin{array}{cccccccccccccccccccccccccccccccccccc$

### **RATINGS** (at T<sub>A</sub>=25 C unless otherwise specified)

Limiting values			<i>135</i>	137	<i>139</i>	
Collector-base voltage (open emitter)	$V_{CBO}$	max.	45	60	100	V
Collector-emitter voltage (open base)	$V_{C\!E\!O}$	max.	45	60	<i>80</i>	V
Emitter-base voltage (open collector)	$V_{EBO}$	max.		5.0		V

Collector current	$I_C$	max.		1.5		$\boldsymbol{A}$
Base current	$I_B$	max.		0.5		$\boldsymbol{A}$
Total power dissipation up to $T_A = 25^{\circ}C$	$P_{tot}$	max.		1.25		W
Derate above 25°C	_	max		10		mW/℃
Total power dissipation up to $T_C = 25^{\circ}C$	$P_{tot}$	max.		12.5		W
Derate above 25°C	_	max		100		mW/℃
Junction temperature	$T_{ij}$ $T_{stg}$	max.	0.5	150	170	${}^{\!$
Storage temperature	1 <sub>stg</sub>		−65 to +150		150	${\mathscr C}$
THERMAL RESISTANCE						
From junction to case	$R_{thj-c}$			10		CW
From junction to ambient	$R_{th j-a}$			100		CW
CHARACTERISTICS						
$T_{amb} = 25^{\circ}C$ unless otherwise specified						
1			<i>135</i>	137	<i>139</i>	
Collector cutoff current						
$I_E = 0; \ V_{CB} = 30 \ V$	$I_{CBO}$	max.		0.1		$\mu A$
$I_E = 0$ ; $V_{CB} = 30 \ V$ ; $T_C = 125 ^{\circ}C$	$I_{CBO}$	max.		10		$\mu A$
Emitter cut-off current						
$I_C = 0$ ; $V_{EB} = 5 V$	$I_{EBO}$	max.		10		$\mu A$
Breakdown voltages						
$I_C = 0.03 \; A; \; I_B = 0$	$V_{CEO(sus)}^*$	min.	45	<i>60</i>	<i>80</i>	V
$I_C = 1 \text{ mA}; I_E = 0$	$V_{CBO}$	min.	45	60	100	V
$I_E = 1 \text{ mA}; I_C = 0$	$V_{EBO}$	min.		5.0		V
Saturation voltage						
$I_C = 0.5 A; I_B = 0.05 A$	$V_{CEsat}^*$	max.		0.5		V
Base-emitter on voltage						
$I_C = 0.5A$ ; $V_{CE} = 2V$	$V_{BE(on)}^*$	max.		1.0		V
D.C. current gain						
$I_C = 0.005 A; V_{CE} = 2 V^*$	$h_{FE}^*$	min.		25		
$I_C = 0.15 A$ ; $V_{CE} = 2 V^{**}$	$h_{FE}^*$	min.		40		
C and A CE	1 L	max.		250		
$I_C = 0.5 A; V_{CE} = 2 V^*$	$h_{FE}^*$	min.		25		
** hfe classification:	-6	min.	40			
HFE CIASSIFICATION.	-0	max.	100			
		шах.	100			
	-10	min.	63			
		max.	160			
	-16	min.	100			
		max.				
	0.7					
	<b>-25</b>	min.	160			
* Pulse test mules width < 200 us duty ou	ala < 20/	max.	400			

<sup>\*</sup> Pulse test: pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2%.

#### **Notes**

#### **Disclaimer**

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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